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HW #3

MENG 7891

For direct methane oxidation in an SOFC at the anode, the net reaction is —



At the anode, $\text{CH}_4 + 2\text{H}_2\text{O} \rightarrow \text{CO}_2 + 8\text{H}^+ + 8\text{e}^-$

Cathode, $\text{O}_2 + 4\text{e}^- \rightarrow 2\text{O}^{2-}$

Thus 1 mole of CH_4 reacts with 2 moles of $\text{O}_2 \rightarrow 8$ electrons transferred.

Given, operating temperature, $T = 700^\circ\text{C} = 973\text{ K}$

Gas pressure, $P = 1\text{ atm} = 101325\text{ Pa}$

Gas constant, $R = 8.314\text{ J/mole}\cdot\text{K}$

Faraday's constant, $F = 96485\text{ C/mol}$.

Charge transfer coefficient, $\alpha = 0.5$

Effective diffusivity of O_2 , $D_e^{\text{eff}} = 3.66 \times 10^{-7}\text{ m}^2/\text{s}$

Ohmic potential, $\eta_{\text{Ohmic}} = j \cdot R_{\text{Ohmic}} = 10 \times 0.1\text{ }\Omega\cdot\text{cm}^2$
 $= 10^4 \times 1 \times 10^{-5}\text{ }\Omega\cdot\text{m}^2$
 $= 0.1\text{ V}$

Total molar concentration from ideal gas law —

$$C_{\text{total}} = \frac{P}{RT} = \frac{101325}{8.314 \times 973} = 12.53\text{ mol/m}^3$$

From volume fractions,

$$\text{O}_2 (18\%), C_{\text{O}_2} = 0.18 \times 12.53 = 2.26\text{ mol/m}^3$$

$$\text{CH}_4 (60\%), C_{\text{CH}_4} = 0.60 \times 12.53 = 7.52\text{ mol/m}^3$$

Exchange current density, at cathode,

$$\begin{aligned} I_0^c &= 3.8 \times 10^6 \exp\left(-\frac{8170}{T}\right) \times C_{O_2} \\ &= 3.8 \times 10^6 \exp\left(-\frac{8170}{273}\right) \times 2.26 \\ &= 3117.86 \text{ A/m}^2 \end{aligned}$$

$$\begin{aligned} \text{At anode, } I_0^a &= 1.3 \times 10^6 \exp\left(-\frac{8427}{T}\right) \times C_{CH_4} \\ &= 1.3 \times 10^6 \exp\left(-\frac{8427}{273}\right) \times 7.52 \\ &= 38768.34 \text{ A/m}^2 \end{aligned}$$

concentration overpotential,

$$\eta_{conc} = -\frac{RT}{nF} \ln\left(\frac{C_s}{C_b}\right) \quad \begin{array}{l} C_b = \text{bulk concentration} \\ C_s = \text{surface concentration} \end{array}$$

$$C_s = C_b - \frac{j \cdot \delta}{nAD}$$

At $j = 1.0 \text{ A/cm}^2 = 10^4 \text{ A/m}^2$, diffusion layer thickness at cathode/electrolyte interface, $\delta = 10 \mu\text{m} = 10 \times 10^{-6} \text{ m}$

$$\text{Cathode: } C_{s,O_2} = 2.26 - \frac{10^4 \times 10 \times 10^{-6}}{8 \times 96485 \times 3.66 \times 10^{-7}} = 2.20$$

$$\eta_{c,conc} = -\frac{8.314 \times 973}{8 \times 96485} \ln\left(\frac{2.20}{2.26}\right) = 0.00179 \text{ V}$$

$$\text{Anode: } C_{s,CH_4} = 7.52 - \frac{10^4 \times 200 \times 10^{-6}}{8 \times 96485 \times 9.66 \times 10^{-7}} = 7.30$$

$[D_a^{\text{eff}} = 9.66 \times 10^{-7}]$

$$\eta_{a,conc} = -0.00463 \text{ V}$$

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Activation ^{over} potential, $\eta_{act} = \frac{RT}{\alpha n F} \sinh^{-1} \left(\frac{j}{2i_0} \right)$

At $j = 10^4 \text{ A/m}^2$,

Cathode: $\eta_{c,act} = \frac{8.314 \times 973}{0.5 \times 8 \times 96485} \sinh^{-1} \left(\frac{10^4}{2 \times 3117.86} \right)$
 $= 0.03518 \text{ V}$

Anode: $\eta_{a,act} = \frac{8.314 \times 973}{0.5 \times 8 \times 96485} \sinh^{-1} \left(\frac{10^4}{2 \times 38768.34} \right)$
 $= 0.00610 \text{ V}$

Total overpotential $= \eta_{c,act} + \eta_{ohmic} + \eta_{c,conc} + \eta_{a,conc} + \eta_{a,act}$

$\eta_{total} = 0.03518 + 0.1 + 0.00179 + 0.00463$
 $+ 0.00610$

$\eta_{total} = 0.1477 \text{ V}$

Assume open-circuit voltage, $E_0 = 1.1 \text{ V}$

$V_{operating} = E_0 - \eta_{total}$
 $= (1.1 - 0.1477) \text{ V}$

$V_{op} = 0.9523 \text{ V}$

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Concentration over potential at $j = 2.5 \text{ A/cm}^2$
 $= 2.5 \times 10^4 \text{ A/m}^2$

$$\text{Cathode: } c_{s, O_2} = 2.26 - \frac{2.5 \times 10^4 \times 10 \times 10^{-6}}{8 \times 96485 \times 3.66 \times 10^{-7}} \\ = 2.18 \text{ mol/m}^3$$

$$\eta_{c, \text{conc}} = - \frac{RT}{nF} \ln\left(\frac{2.18}{2.26}\right) = 0.00523 \text{ V}$$

$$\text{Anode: } c_{s, CH_4} = 7.52 - \frac{2.5 \times 10^4 \times 200 \times 10^{-6}}{8 \times 96485 \times 9.66 \times 10^{-7}} \\ = 6.97 \text{ mol/m}^3$$

$$\eta_{a, \text{conc}} = - \frac{RT}{nF} \ln\left(\frac{6.97}{7.52}\right) = 0.02337 \text{ V}$$

Activation overpotential's, at $j = 2.5 \text{ A/cm}^2$

$$\text{Cathode: } \eta_{c, \text{act}} = \frac{RT}{\alpha n F} \sinh^{-1}\left(\frac{j}{2i_{0, c}}\right) \\ = \frac{8.314 \times 273}{0.5 \times 8 \times 96485} \sinh^{-1}\left(\frac{2.5 \times 10^4}{2 \times 3117.86}\right) \\ = 0.05377 \text{ V}$$

$$\text{Anode: } \eta_{a, \text{act}} = \frac{RT}{\alpha n F} \sinh^{-1}\left(\frac{2.5 \times 10^4}{2 \times 38768.34}\right) \\ = 0.01432 \text{ V}$$

$$\text{Ohmic overpotential} = j \cdot R_{\text{ohmic}} = 2.5 \times 10^4 \times 1 \times 10^{-5} \\ = 0.25 \text{ V}$$

$$\text{Total Overpotential, } \eta_{\text{total}} = 0.00523 + 0.02337 + 0.05377 + 0.01432 + 0.25$$

$$\boxed{\eta_{\text{total}} = 0.3467 \text{ V}}$$

$$\text{operating voltage, } V_{\text{operating}} = E_0 - \eta_{\text{total}}$$

$$= (1.1 - 0.3467) \text{ V}$$

$$\boxed{V_{\text{operating}} = 0.7533 \text{ V}}$$

→ The operating voltage drops from 0.95 V to 0.75 V as current density increases.

→ Ohmic loss is the dominant loss at higher current density.